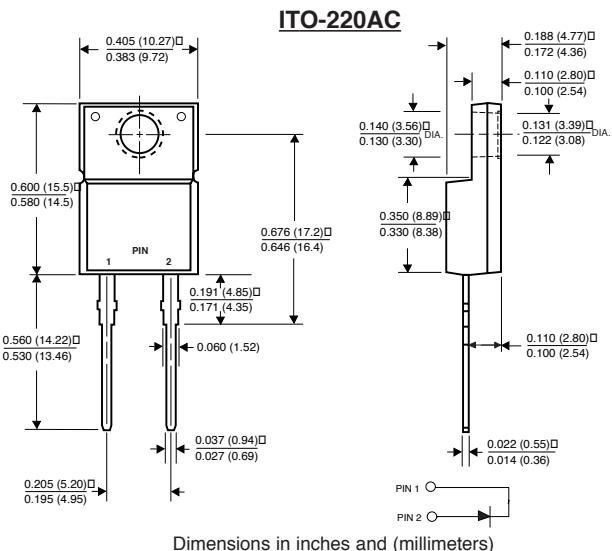


MBRF1035 THRU MBRF1060

SCHOTTKY ISOLATED PLASTIC RECTIFIER
Reverse Voltage - 35 to 60 Volts Forward Current - 10.0 Amperes



FEATURES

- ◆ Isolated plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guardring for overvoltage protection
- ◆ High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case



MECHANICAL DATA

- Case:** JEDEC ITO-220AC fully overmolded plastic body
Terminals: Leads solderable per MIL-STD-750, Method 2026
Polarity: As marked
Mounting Position: Any
Mounting Torque: 5 in. - lbs. max.
Weight: 0.08 ounces, 1.81 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	MBRF1035	MBRF1045	MBRF1050	MBRF1060	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	Volts
Maximum working peak reverse voltage	V _{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage	V _{DC}	35	45	50	60	Volts
Maximum average forward rectified current (SEE FIG. 1)	I _(AV)	10.0				Amps
Peak repetitive forward current at T _c =135°C (square wave 20 KHz)	I _{FRM}	20.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150.0				Amps
Peak repetitive reverse surge current (NOTE 1)	I _{RRM}	1.0	0.5			Amps
Voltage rate of change (rated V _R)	dv/dt	10,000				V/ μ s
Maximum instantaneous forward voltage at (NOTE 2) I _F =10A, T _c =25°C I _F =10A, T _c =125°C I _F =20A, T _c =25°C I _F =20A, T _c =125°C	V _F	- 0.57 0.84 0.72	0.80 0.70 0.95 0.85			Volts
Maximum instantaneous reverse current at rated DC blocking voltage T _c = 25°C (NOTE 2) T _c =125°C	I _R	0.10 15.0				mA mA
Maximum thermal resistance, junction to case	R _{θJC}	4.0				°C/W
Operating junction temperature range	T _J	-65 to +150				°C
Storage temperature range	T _{STG}	-65 to +175				°C
RMS Isolation voltage from terminals to heatsink with RH ≤ 30%	V _{ISOL}	4500 (NOTE 3) 3500 (NOTE 4) 1500 (NOTE 5)				Volts

NOTES:

(1) 2.0μs pulse width, f=1.0 KHz

(2) Pulse test: 300μs pulse width, 1% duty cycle

(3) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset.

(4) Clip mounting (on case), where leads do overlap heatsink.

(5) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19").

2/18/99

RATINGS AND CHARACTERISTIC CURVES MBRF1035 THRU MBRF1060

